



April 2014

FQD17P06 / FQU17P06

P-Channel QFET® MOSFET

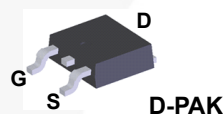
-60 V, -12 A, 135 mΩ

Description

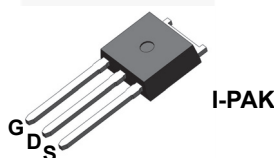
This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

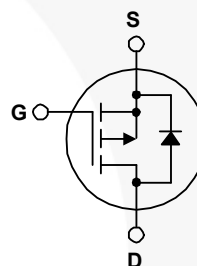
- -12 A, -60 V, $R_{DS(on)} = 135 \text{ m}\Omega$ (Max.) @ $V_{GS} = -10 \text{ V}$, $I_D = -6 \text{ A}$
- Low Gate Charge (Typ. 21 nC)
- Low C_{rss} (Typ. 80 pF)
- 100% Avalanche Tested



D-PAK



I-PAK



Absolute Maximum Ratings

$T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FQD17P06 / FQU17P06	Unit
V_{DSS}	Drain-Source Voltage	-60	V
I_D	Drain Current	- Continuous ($T_C = 25^\circ\text{C}$)	A
		- Continuous ($T_C = 100^\circ\text{C}$)	A
I_{DM}	Drain Current	- Pulsed (Note 1)	A
V_{GSS}	Gate-Source Voltage	± 25	V
E_{AS}	Single Pulsed Avalanche Energy	(Note 2) 300	mJ
I_{AR}	Avalanche Current	(Note 1) -12	A
E_{AR}	Repetitive Avalanche Energy	(Note 1) 4.4	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3) -7.0	V/ns
P_D	Power Dissipation ($T_A = 25^\circ\text{C}$) *	2.5	W
	Power Dissipation ($T_C = 25^\circ\text{C}$)	44	W
	- Derate above 25°C	0.35	W/ $^\circ\text{C}$
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds.	300	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	FQD17P06 / FQU17P06	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	2.85	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	110	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (*1 in ² Pad of 2-oz Copper), Max.	50	

* When mounted on the minimum pad size recommended (PCB Mount)

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQD17P06TM	FQD17P06	DPAK	Tape and Reel	330 mm	16 mm	2500 units
FQU17P06TU	FQU17P06	IPAK	Tube	N/A	N/A	70 units

Electrical Characteristics T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = -250 μA	-60	--	--	V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = -250 μA, Referenced to 25°C	--	-0.06	--	V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -60 V, V _{GS} = 0 V	--	--	-1	μA
		V _{DS} = -48 V, T _C = 125°C	--	--	-10	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = -25 V, V _{DS} = 0 V	--	--	-100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = 25 V, V _{DS} = 0 V	--	--	100	nA
On Characteristics						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = -250 μA	-2.0	--	-4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = -10 V, I _D = -6.0 A	--	0.11	0.135	Ω
g _{FS}	Forward Transconductance	V _{DS} = -30 V, I _D = -6.0 A	--	8.7	--	S
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{DS} = -25 V, V _{GS} = 0 V, f = 1.0 MHz	--	690	900	pF
C _{oss}	Output Capacitance		--	325	420	pF
C _{rss}	Reverse Transfer Capacitance		--	80	105	pF
Switching Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{DD} = -30 V, I _D = -8.5 A, R _G = 25 Ω (Note 4)	--	13	35	ns
t _r	Turn-On Rise Time		--	100	210	ns
t _{d(off)}	Turn-Off Delay Time		--	22	55	ns
t _f	Turn-Off Fall Time		--	60	130	ns
Q _g	Total Gate Charge	V _{DS} = -48 V, I _D = -17 A, V _{GS} = -10 V (Note 4)	--	21	27	nC
Q _{gs}	Gate-Source Charge		--	4.2	--	nC
Q _{gd}	Gate-Drain Charge		--	10	--	nC
Drain-Source Diode Characteristics and Maximum Ratings						
I _S	Maximum Continuous Drain-Source Diode Forward Current		--	--	-12	A
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current		--	--	-48	A
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = -12 A	--	--	-4.0	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = -17 A,	--	92	--	ns
Q _{rr}	Reverse Recovery Charge	dl _F / dt = 100 A/μs	--	0.32	--	μC

NOTES:

1. Repetitive rating: pulse-width limited by maximum junction temperature.
2. L = 2.4 mH, I_{AS} = -12 A, V_{DD} = -25 V, R_G = 25 Ω, starting T_J = 25°C.
3. I_{SD} ≤ -17 A, di/dt ≤ 300 A/μs, V_{DD} ≤ BV_{DSS}, starting T_J = 25°C.
4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

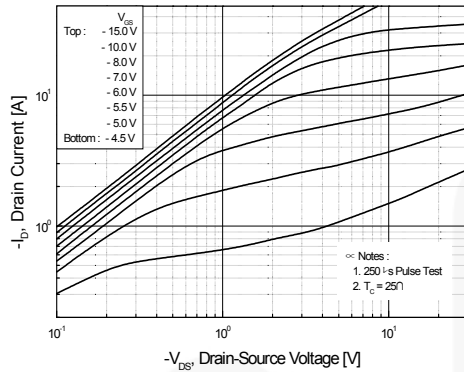


Figure 1. On-Region Characteristics

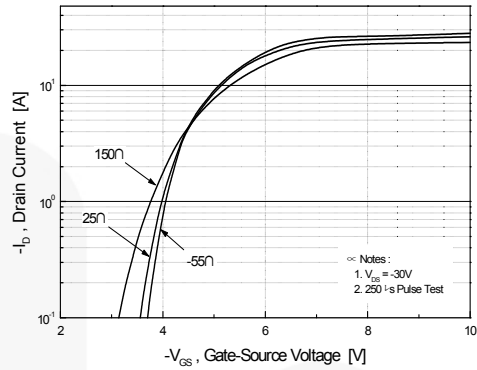


Figure 2. Transfer Characteristics

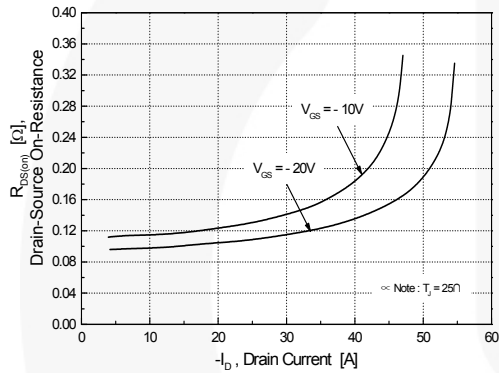


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

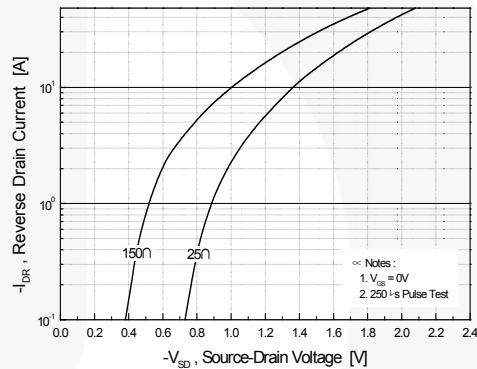


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

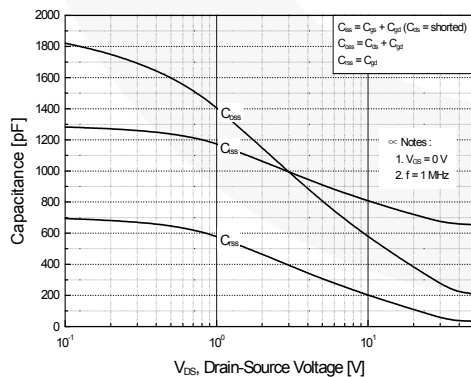


Figure 5. Capacitance Characteristics

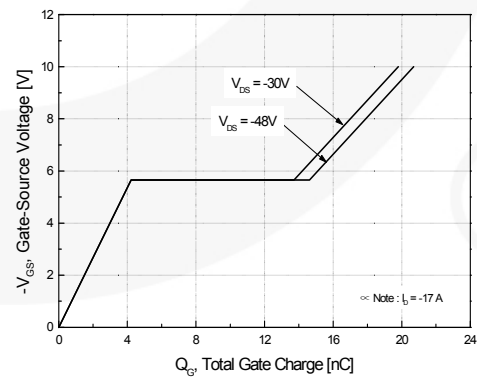


Figure 6. Gate Charge Characteristics

Typical Performance Characteristics (Continued)

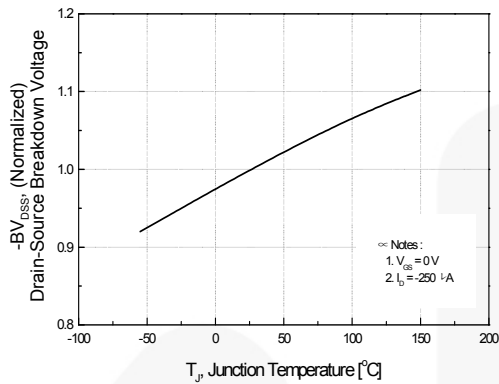


Figure 7. Breakdown Voltage Variation vs. Temperature

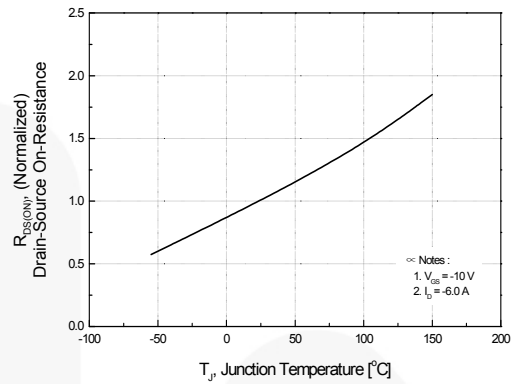


Figure 8. On-Resistance Variation vs. Temperature

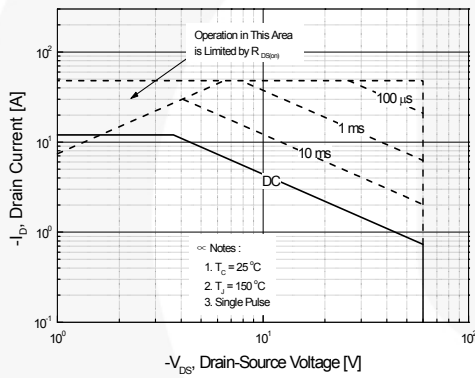


Figure 9. Maximum Safe Operating Area

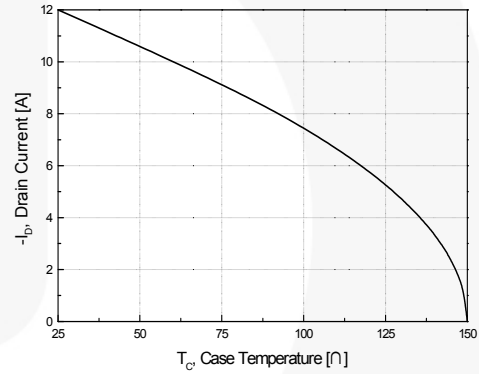


Figure 10. Maximum Drain Current vs. Case Temperature

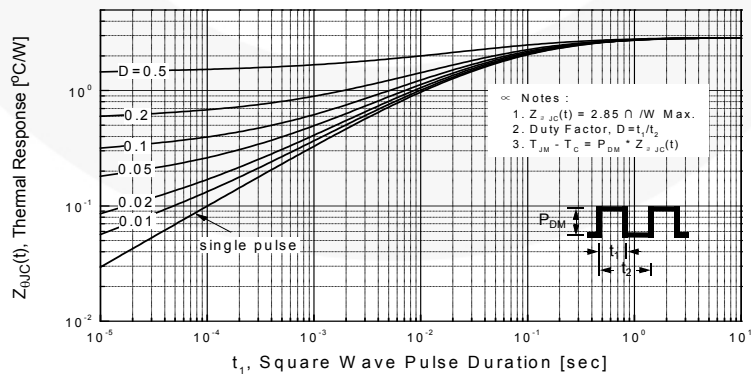


Figure 11. Transient Thermal Response Curve

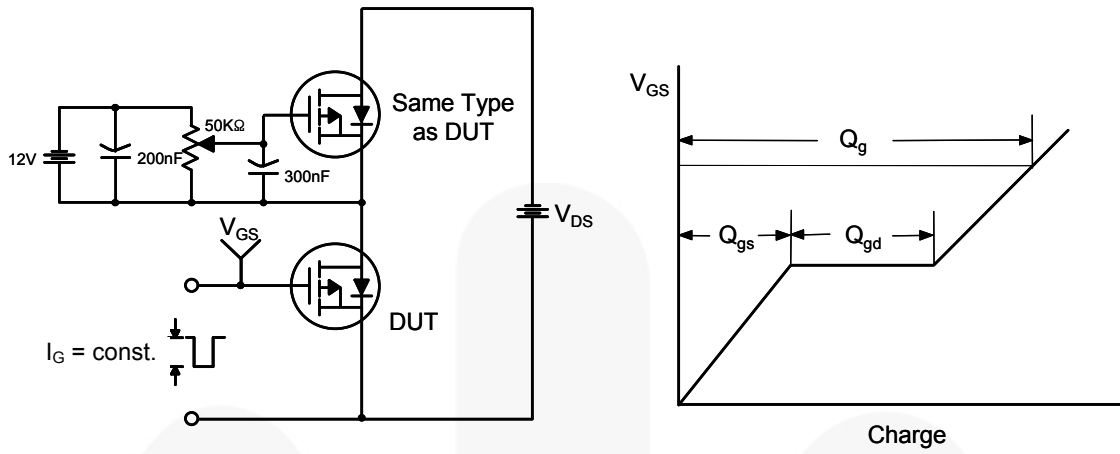


Figure 12. Gate Charge Test Circuit & Waveform

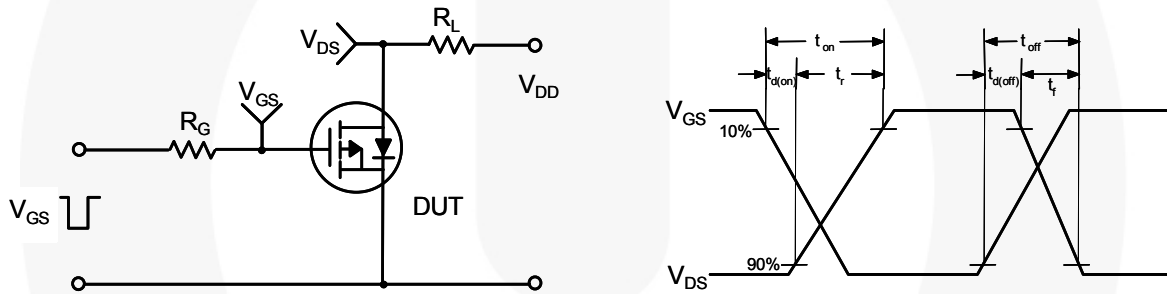


Figure 13. Resistive Switching Test Circuit & Waveforms

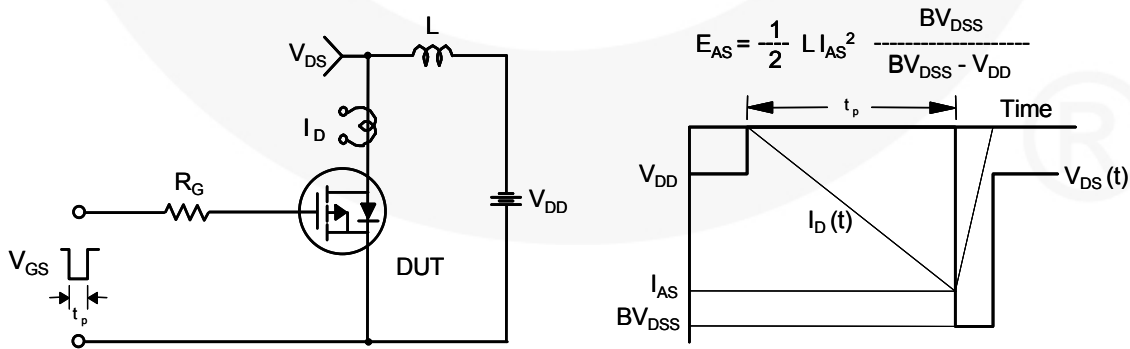


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

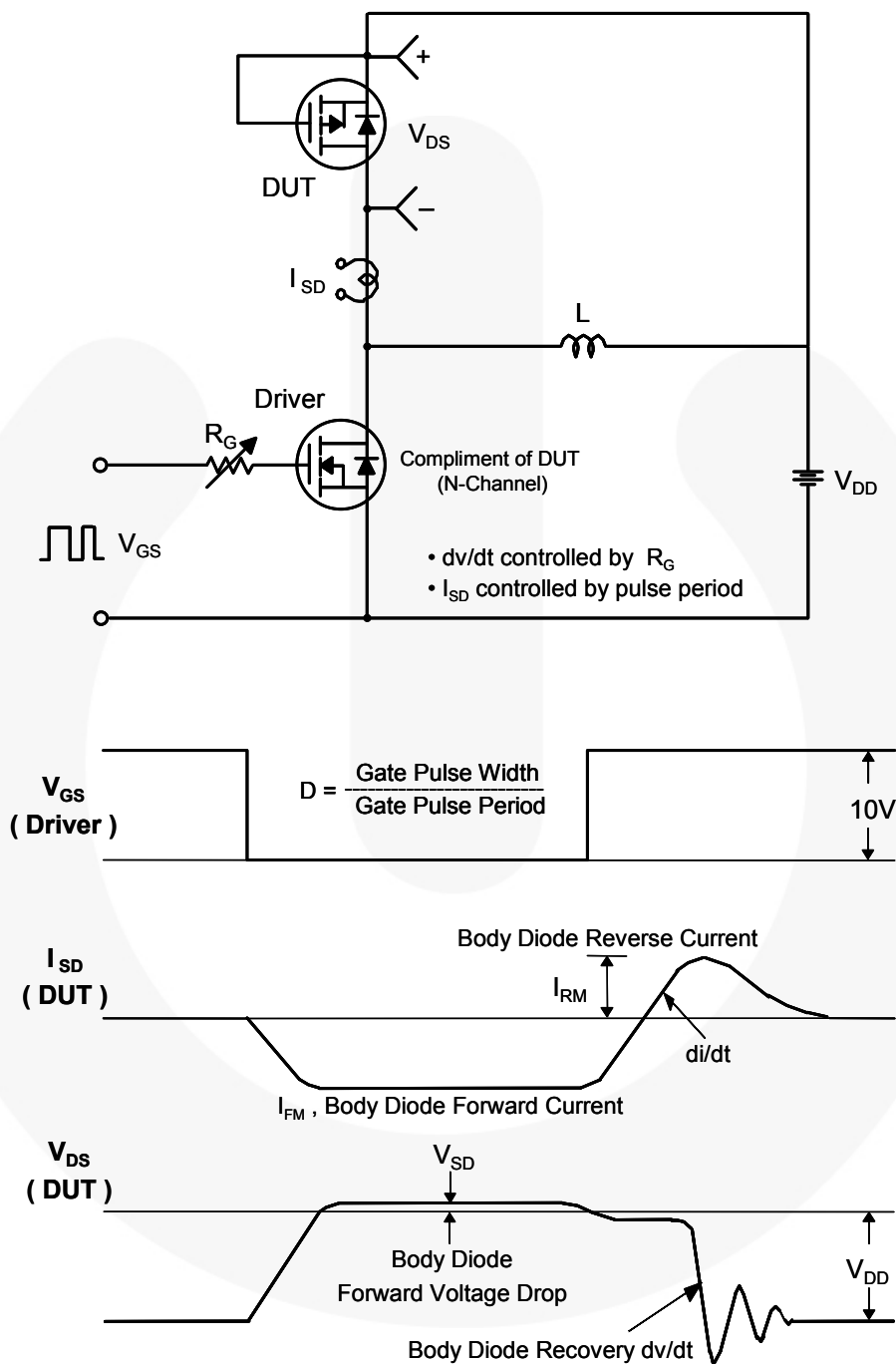


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

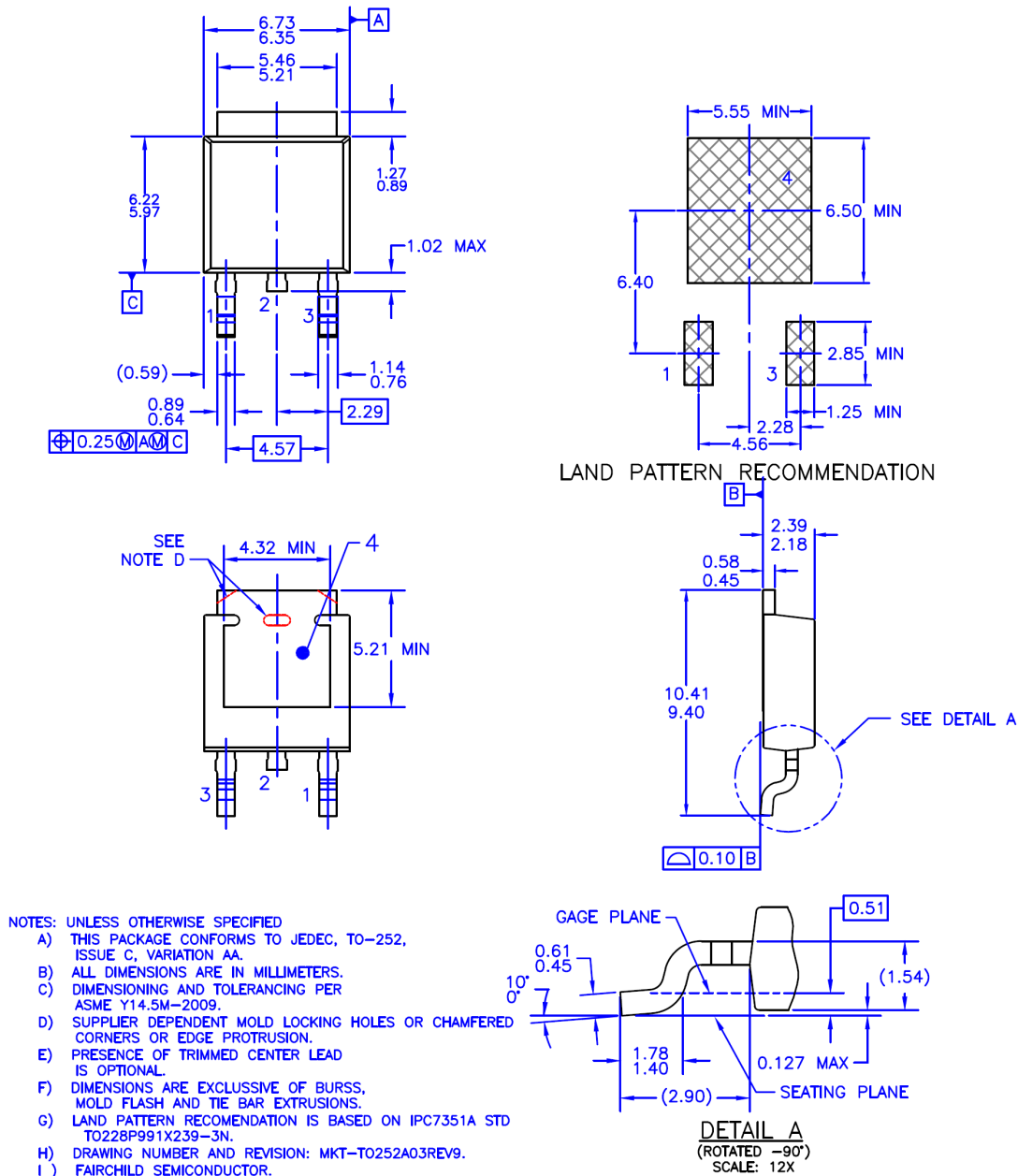


Figure 16. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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Mechanical Dimensions

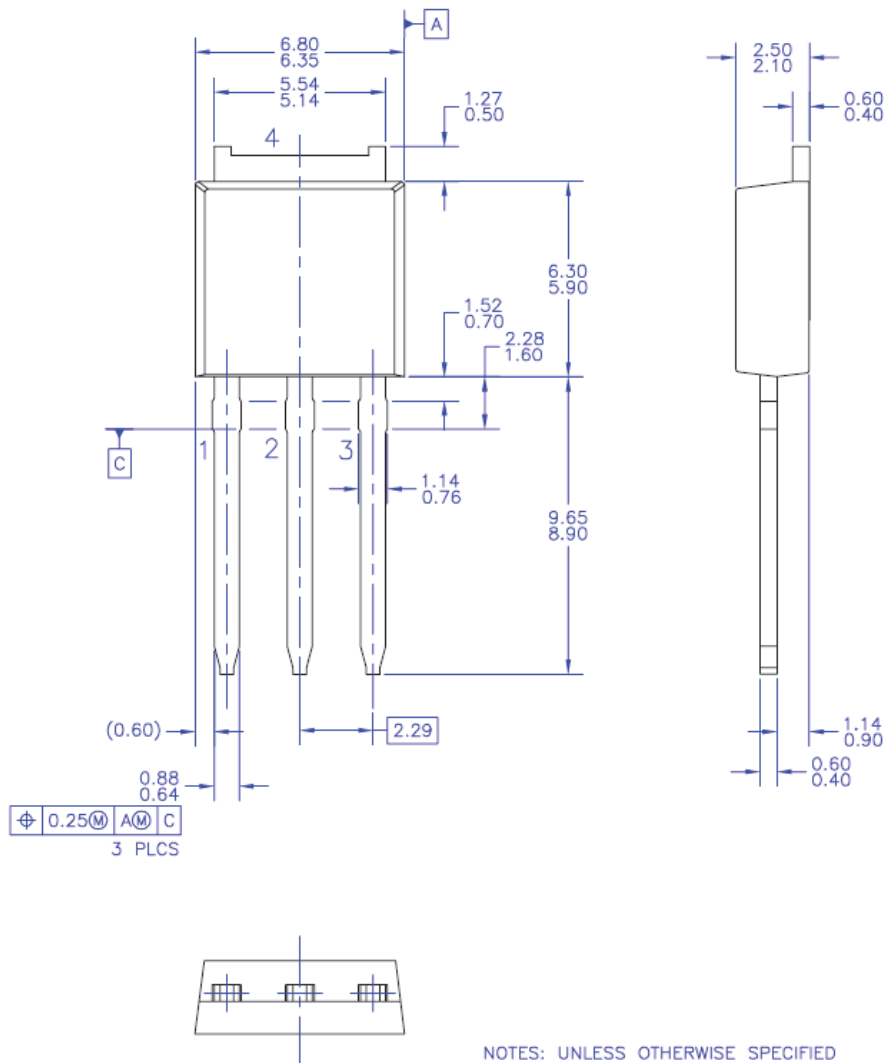


Figure 17. TO251 (I-PAK), Molded, 3-Lead

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